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Synthetic history matters: understanding the structure–property evolution in CsSn_xGe_{1-x}Br₃ perovskites

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Metal halide perovskites and related perovskite-inspired materials continue to attract attention for next-generation photovoltaic applications. Compositional synthetic design remains the preferred method for exploring property manipulation and for gaining new insights into material stability and behaviour. This study explores the CsSn_xGe_{1-x}Br₃ perovskite series to elucidate how composition and preparation method, including solvent, mechanochemical, and high-temperature synthesis, directly influence the chemical structure and optoelectronic properties. Various analytical techniques, including solid-state nuclear magnetic resonance (NMR) spectroscopy, nuclear quadrupole resonance (NQR) spectroscopy, powder X-ray diffraction (XRD), diffuse reflectance spectroscopy, and electron microscopy, have been employed to characterize the local atomic environment, long-range crystallographic structure, morphology, and optical properties of the synthesized CsSn_xGe_{1-x}Br₃ perovskites. NMR and NQR reveal unique chemical environments and electric field gradients, and how the atomic structure responds to different synthetic conditions across the perovskite system. Paired with long-range diffraction and microscopy-based techniques, these methods provide detailed insight into crystallographic phase, B-site mixing, and domain formation across different compositions and syntheses.

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Introduction

Metal halide perovskites, ABX₃ [A⁺ = Cs, formamidinium (FA), methylammonium (MA); B²⁺ = Ge, Sn, Pb; X⁻ = Cl, Br, I], have served as promising candidates for optical applications since MAPbI₃ was first demonstrated to be an effective absorber layer for dye-sensitized solar cells.¹ Owing to their favourable optoelectronic properties, metal halide perovskites have naturally extended to applications in light-emitting diodes, photovoltaics, sensing, radiation detection, and lasing.²⁻⁵ Perovskites feature a high degree of compositional tunability, high defect tolerance, and diverse and robust methods for their synthesis, enabling access to desirable semiconducting properties. The compositional and structural diversity of halide perovskites and related systems creates opportunities

for property manipulation through site disorder, heterovalent substitution, and the introduction of vacancies, while posing challenges for obtaining direct insight into how these structures evolve and adapt across their unique A, B, and X sites.^{3,5-17}

The lead halide perovskites are most commonly used in perovskite solar cells, but suffer from intrinsic instability,¹⁸⁻²⁶ pose toxicity concerns,^{8,11,17,27} and rely on organic solvents for solution processing. In particular, hybrid lead halide perovskites are prone to degradation from moisture or heat,^{18,20,23,28,29} and they exhibit structural instability arising from phase changes, segregation, and domain formation.^{23,30-34} To counteract these effects, various ion substitutions have been performed at the A and X sites^{3,4} with new emphasis on the B site by replacing Pb with Sn or Ge.^{6,8,11} For example, mixing Pb and Sn on the B site has yielded devices with photoconversion efficiencies (PCEs) exceeding 20%.³⁵⁻³⁹ Sn-containing perovskites have been widely studied, with PCEs approaching 15%,⁴⁰ whereas Ge-containing perovskites have been less well studied and show poorer performance.^{41,42} For Sn- and Ge-containing perovskites, the primary mechanism of degradation involves the oxidation of the B atom from divalent to tetravalent states,^{6,16,43-47} which disrupts the network of

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corner-sharing octahedra responsible for many dynamic processes.^{48–52} Mixing Sn and Ge at the B-site has been shown to improve photovoltaic performance and stability compared to pure Pb-free compositions.^{6,11,16,45–47,53} For example, CsSn_{0.5}Ge_{0.5}I₃ exhibits a PCE of 7% and improved stability relative to CsGeI₃ or CsSnI₃, through the formation of a passivating oxide layer.⁴⁵ A hybrid Sn–Ge perovskite with 5 mol% Ge gave a PCE of nearly 8%.⁴⁴ Efforts into understanding the formation and stability of Sn- and Ge-containing perovskites is desirable to continue to parse the structure–property relationships that govern material performance.

The relationships between processing conditions, composition, and properties of mixed Sn–Ge perovskites can be clarified by examining the structures through characterization techniques that probe both long-range order and local environments. Magnetic resonance techniques that distinguish the local chemical and electronic environments with atomic resolution are particularly suited to the study of perovskites and their wide-ranging dynamic phenomena. Solid-state nuclear magnetic resonance (NMR) spectroscopy has been applied to various perovskites,^{54–59} providing information on substituents, phase segregation, and dynamics at the atomic scale, with each crystallographic site investigated using different reporter nuclei.^{15,23,33,34,60–62} Perovskites containing appropriately accessible nuclei may be amenable to nuclear quadrupole resonance (NQR) spectroscopy, in which the quadrupolar interaction can be highly sensitive to small changes in local structure and defects.⁵⁸

This study examines the solid-solution CsSn_xGe_{1–x}Br₃ and explores how their structures and optical properties are influenced by three preparative routes: solvent synthesis (SS), mechanochemical synthesis (MCS) by high-energy ball milling, and high-temperature (HT) solid-state reaction. The structures were evaluated by powder and single crystal X-ray diffraction (XRD) and by NMR (¹³³Cs, ¹¹⁹Sn, ⁷³Ge) and NQR (⁸¹Br) spectroscopy.

Results and discussion

XRD, ¹³³Cs NMR spectra, and band gaps of CsGeBr₃, CsSn_{0.5}Ge_{0.5}Br₃, and CsSnBr₃

Contributing to previous examples of Sn–Ge perovskites,^{16,44–46,53,63} this work describes the solid solution CsSn_xGe_{1–x}Br₃ prepared as microcrystalline bulk powders. Because the synthetic method can influence structure and physical properties,^{60,62,64,65} samples of CsGeBr₃, CsSn_{0.5}Ge_{0.5}Br₃, and CsSnBr₃ were prepared in three ways (SS, MCS, and HT). They were characterized by XRD, NMR and NQR spectroscopy, with optical band gap measurements (Fig. 1 and Table 1).

The powder XRD patterns confirm the presence of the expected phases (Fig. 1a–c), whose relative amounts and cell parameters were extracted from Rietveld refinements (Fig. S1–S3 and Tables S1 and S2). The CsGeBr₃ samples contained a trigonal perovskite phase (KBrO₃-type, space group *R3m*),

whose lower symmetry is evident by peak splitting, whereas the CsSnBr₃ samples possess a cubic phase (CaTiO₃-type, space group *Pm3̄m*). On first inspection, the CsSn_{0.5}Ge_{0.5}Br₃ samples appeared to contain both phases in different amounts depending on the synthetic method: the trigonal and cubic phases were present in roughly equal proportions in the SS-prepared sample, whereas the cubic phase was more prevalent in the MCS- and HT-prepared samples. This observation suggests a miscibility gap between a Ge-rich trigonal phase and a Sn-rich cubic phase. However, the peak splitting originating from a trigonal distortion can be difficult to discern. It is possible to refine the patterns assuming that only a cubic phase is present for the intermediate members, especially for the MCS-prepared samples where the peaks are visibly broadened compared to the SS-prepared samples. All samples also contained small amounts of other phases, such as Cs₂(Ge,Sn)Br₆, Cs₄(Ge,Sn)Br₆, (Ge,Sn)Br₂, CsBr, CsOH, and (Ge,Sn)O₂, which tended to increase upon exposure to air and moisture (relative humidity of ~60%) over 9 h during the data collection, implying that they are decomposition byproducts (Fig. S1–S3 and Table S2). For comparison, thin films of the solid solution CsSn_xGe_{1–x}Br₃ have been previously fabricated by spray deposition, with a transition from trigonal to cubic structures indicated at *x* = 0.23.⁵³ Additional evidence would thus be helpful to ascertain whether the CsSn_{0.5}Ge_{0.5}Br₃ samples prepared here correspond to a single phase with the stated nominal composition, or a mixture of two phases with Ge- and Sn-rich compositions.

Initially, single crystals were sought within the MCS- and SS-prepared samples, but no suitably sized specimens could be found, which is unsurprising because these routes take place at room temperature or with fast precipitation. Instead, single crystals were found within the HT-prepared CsGe_{0.5}Sn_{0.5}Br₃ sample for structure determination. The crystals exhibited slightly different colours and morphology, so multiple crystals were selected for data collection. Structure refinements were guided by previous determinations of the end members: CsGeBr₃ crystallizes in the trigonal space group *R3m* in which Ge-centred octahedra are slightly distorted because of the stereochemically active lone pair,⁶⁶ in contrast to CsSnBr₃ which adopts the ideal undistorted perovskite structure in the cubic space group *Pm3̄m*. The results for two representative crystals of CsGe_{0.5}Sn_{0.5}Br₃ are presented, in which both trigonal and cubic models were considered (Tables S3–S5). The two models were essentially indistinguishable, as detailed in the SI, in terms of their agreement factors and their metrical details. For example, the bond angles around the tetrel atoms lie in the range of 88–92° in the trigonal model. An interpretation based on these results is that whatever distortions that Ge-centred octahedra may undergo locally, they would be masked by the disorder with Sn atoms centred within ideal octahedra. In common with other perovskite structures, the Br atoms experience slightly elevated displacement parameters relative to the other atoms, which may reflect the combined effects of slightly distorted Ge-centred octahedra and undistorted Sn-centred octahedra.



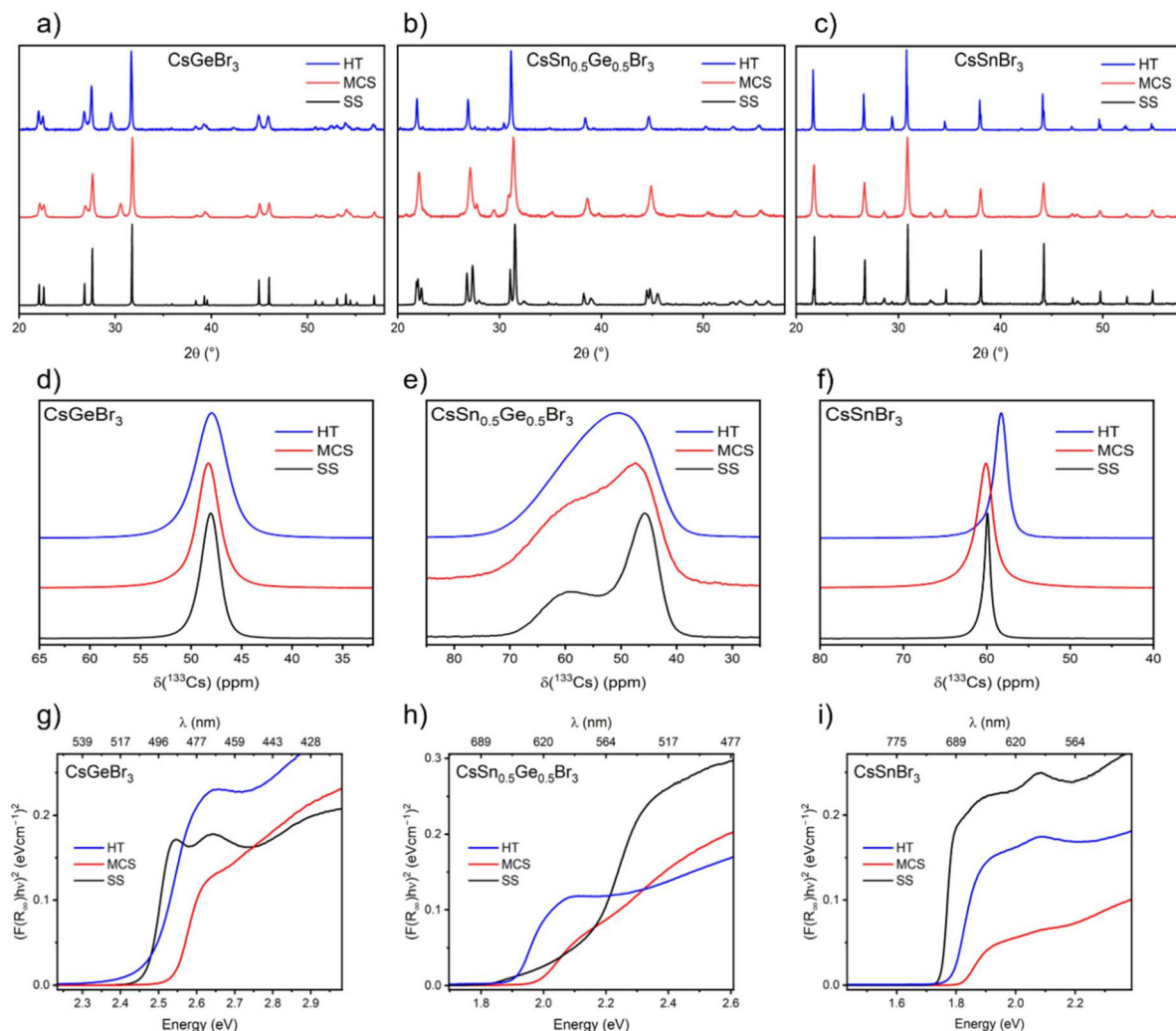


Fig. 1 (a–c) Powder XRD patterns, (d–f) ¹³³Cs NMR spectra, and (g–i) diffuse reflectance spectra for CsGeBr₃, CsSn_{0.5}Ge_{0.5}Br₃, and CsSnBr₃ samples prepared via SS, MCS, and HT routes.

Cesium-133 is a receptive NMR probe nucleus (abundance = 100%, $I = 7/2$, $\gamma = 3.5277 \times 10^7 \text{ rad T}^{-1} \text{ s}^{-1}$, $Q = -0.34 \text{ fm}^2$) that is sensitive to changes in local symmetry introduced by site disorder in CsSn_xGe_{1-x}Br₃ (Fig. 1d–f).^{62,65,67,68} The end members show a single resonance with an isotropic chemical shift $\delta_{\text{iso}} = 48 \text{ ppm}$ for trigonal CsGeBr₃ and $\delta_{\text{iso}} = 60 \text{ ppm}$ for cubic CsSnBr₃. For HT-prepared CsSnBr₃, the resonance shifts to slightly lower frequency, which has been noted previously for samples prepared this way,⁶⁵ and correlates with shifts to higher frequency in the ¹¹⁹Sn NMR and ⁸¹Br NQR spectra. For all SS-prepared samples, the ¹³³Cs NMR resonance is narrower, which suggests greater ordering and fewer defects within the microcrystalline particles compared to samples prepared via MCS or HT methods. For all CsSn_{0.5}Ge_{0.5}Br₃ samples, the resonance spans over a range of 40–70 ppm, encompassing the region expected for the resonances for trigonal CsGeBr₃ and cubic CsSnBr₃. The ¹³³Cs NMR signal is broad and asymmetric for the HT CsSn_{0.5}Ge_{0.5}Br₃ sample, with more well-resolved

shoulders appearing for the MCS sample, resolving into two peaks for the SS sample.

The ¹³³Cs longitudinal relaxation times (T_1) were measured using the saturation recovery method (Fig. S4–S6 and Table 1). Their variation across samples reflects differences in crystallinity and defect concentrations depending on the synthetic route. For example, the decreasing T_1 values for CsGeBr₃ in the sequence of 501 s for SS, 254 s for HT, and 112 s for MCS routes suggest that the defect concentration increases in this order. The relaxation curves were fitted satisfactorily by a single-term exponential function for all samples except SS-prepared CsSn_{0.5}Ge_{0.5}Br₃, which required a biexponential function to model two sites, with the longer T_1 value assigned to a Ge-rich phase and the shorter T_1 assigned to a Sn-rich phase. Taken together, the asymmetric ¹³³Cs NMR line shapes and the fitting to two relaxation times for CsSn_{0.5}Ge_{0.5}Br₃ imply the occurrence of different Cs environments in CsSn_{0.5}Ge_{0.5}Br₃, due to phase segregation or domaining, as will be discussed later.



Table 1 Cell parameters, ^{133}Cs spin lattice relaxation times, ^{133}Cs NMR linewidths, and band gaps for $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$ ($x = 0, 0.50, 1$) synthesized via SS, MCS, and HT routes^a

Sample	a (Å)	α (°)	T_1 (s)	FWHM (Hz)	Band gap (eV)
CsGeBr₃ (<i>R3m</i>)					
SS	5.6485	88.73	501	170	2.5
MCS	5.6505	88.84	112	240	2.5
HT	5.6469	88.85	254	290	2.5
CsSn_{0.5}Ge_{0.5}Br₃ (<i>R3m</i>)					
SS	5.6754	88.96	231	560	2.2
MCS	5.6624	89.53	—	—	—
HT	5.7458	89.43	—	—	—
CsSn_{0.5}Ge_{0.5}Br₃ (<i>Pm3m</i>)					
SS	5.5010	90	32	870	1.8
MCS	5.7495	90	31	1450	2.0
HT	5.7391	90	51	1500	1.9
CsSnBr₃ (<i>Pm3m</i>)					
SS	5.8035	90	33	65	1.8
MCS	5.8039	90	24	240	1.8
HT	5.8023	90	25	140	1.8

^a Estimated errors are 0.0002 Å for a , 0.02° for α (except for 90°, which is exact), <0.5 s for T_1 , ± 5 –30 Hz for FWHM, and ± 0.05 eV for band gap. The cell parameters for the trigonal structural models in *R3m* correspond to a primitive rhombohedral cell to facilitate comparison to the cubic model.

The diffuse reflectance spectra show absorption edges corresponding to band gaps of roughly 2.5 eV for CsGeBr₃, 1.8–2.2 eV for CsSn_{0.5}Ge_{0.5}Br₃, and 1.8 eV for CsSnBr₃, as

extracted from Tauc plots (Fig. 1g–i and S7–S9). For the end members CsGeBr₃ and CsSnBr₃, the band gaps for samples prepared by three alternate routes are consistent with previously reported values.^{53,67,69} The band gaps for CsSn_{0.5}Ge_{0.5}Br₃ are intermediate between the end members, but they also show the widest discrepancies depending on the synthetic method. This likely stems from variations in B–X bond lengths and angles, which primarily control the magnitudes of band gaps in ABX₃ perovskites, depending on the preparation route. Of note, SS-prepared CsSn_{0.5}Ge_{0.5}Br₃ appears to show two edges in its diffuse reflectance spectrum, corresponding to band gaps of 1.8 and 2.2 eV, likely stemming from phase-segregated Sn- and Ge-rich compositions in the final product.

Morphology and elemental distribution of CsGeBr₃, CsSn_{0.5}Ge_{0.5}Br₃, and CsSnBr₃

Particle morphologies of the samples were examined by secondary electron micrographs (Fig. 2). For the end members CsGeBr₃ and CsSnBr₃, the SS- and HT-prepared samples contained larger and well-defined particles compared to the MCS-prepared samples, which contained ill-defined particles with jagged edges over a wider size distribution resulting from impact shear forces occurring during ball-milling.^{70,71} EDX analyses showed chemical compositions in agreement with expectations (Fig. S10–S22 and Table S6). For MCS- and HT-

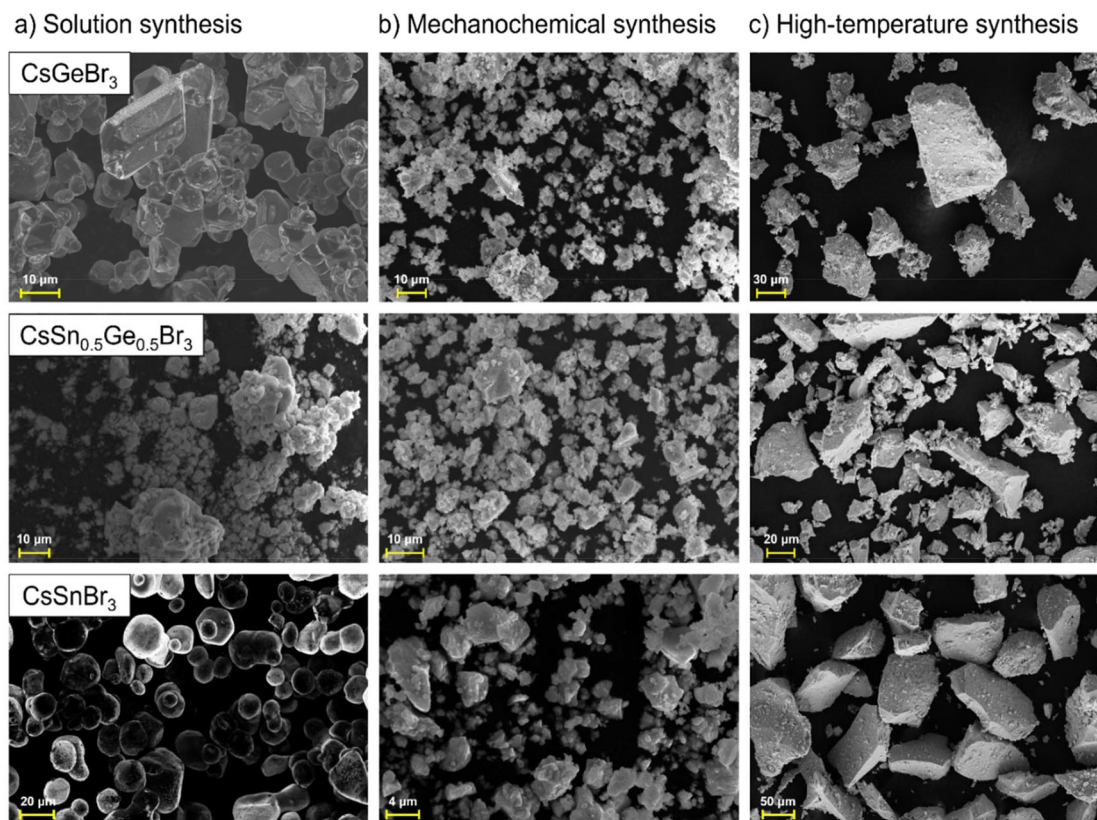


Fig. 2 Secondary electron micrographs for (a) SS, (b) MCS, and (c) HT-prepared samples of CsGeBr₃, CsSn_{0.5}Ge_{0.5}Br₃, and CsSnBr₃.



prepared $\text{CsSn}_{0.5}\text{Ge}_{0.5}\text{Br}_3$ samples, Sn and Ge were uniformly distributed at micron resolution. However, Sn- and Ge-rich regions were apparent in the SS-prepared sample of $\text{CsSn}_{0.5}\text{Ge}_{0.5}\text{Br}_3$ (Fig. S11), as confirmed by an EDX line scan across a cluster showing two starkly distinct phases with compositions of roughly $\text{CsSn}_{0.2}\text{Ge}_{0.8}\text{Br}_3$ and $\text{CsSn}_{0.8}\text{Ge}_{0.2}\text{Br}_3$, with no intervening gradients (Fig. 3).

^{73}Ge NMR of CsGeBr_3 and ^{119}Sn NMR of CsSnBr_3

The tetrel sites in the end members were examined by ^{73}Ge and ^{119}Sn NMR spectroscopy. Among various NMR-accessible nuclei, ^{73}Ge (7.76% abundance, $I = 9/2$, $\gamma = -0.9357 \times 10^7 \text{ rad T}^{-1} \text{ s}^{-1}$, $Q = -19.6 \text{ fm}^2$) is one of the most challenging to study because of its low gyromagnetic ratio and natural abundance, with sensitivity issues further compounded by a moderate quadrupole moment.^{72,73} Even still, it offers direct access to the B-site in Ge-containing perovskites and its quadrupolar nature offers a sensitive means to examine local site symmetry.⁶⁷ The ^{73}Ge NMR spectra were collected for CsGeBr_3 (Fig. 4) and the extracted parameters are compared with computed DFT values (Table 2) for the respective experimentally-

refined SS, MCS, and HT crystal structures. The spectra for SS-, MCS-, and HT-prepared samples are similar (within error), implying that their structures have identical Ge environments regardless of synthetic pathway and agreeing with previous reports.⁶⁷ GIPAW-DFT-calculated ^{73}Ge C_Q values do not change significantly between the different input structures and are consistently overestimated by $\sim 20\%$, as has been seen in earlier work.⁶⁷ Similarly, although the differences in the computed magnetic shieldings differ by $\sim 13 \text{ ppm}$, this is within error of the experimental result across the three compounds. The spectrum of the MCS CsGeBr_3 sample shows a reduced signal-to-noise ratio, consistent with disorder and defects induced by mechanochemical shear forces, reducing nuclear spin-spin relaxation and leading to rapid decay of the NMR signal. Lastly, a small amount (5%) of residual GeBr_4 ,⁷⁴ present in (and an oxidation product of) the starting material, was also detected.

In contrast to the ^{73}Ge NMR spectra for CsGeBr_3 , the chemical shifts in the ^{119}Sn NMR (8.59% abundance, $I = 1/2$, $\gamma = -10.0317 \times 10^7 \text{ rad T}^{-1} \text{ s}^{-1}$) spectra for CsSnBr_3 showed significant variation, spanning over 1000 ppm depending on the syn-

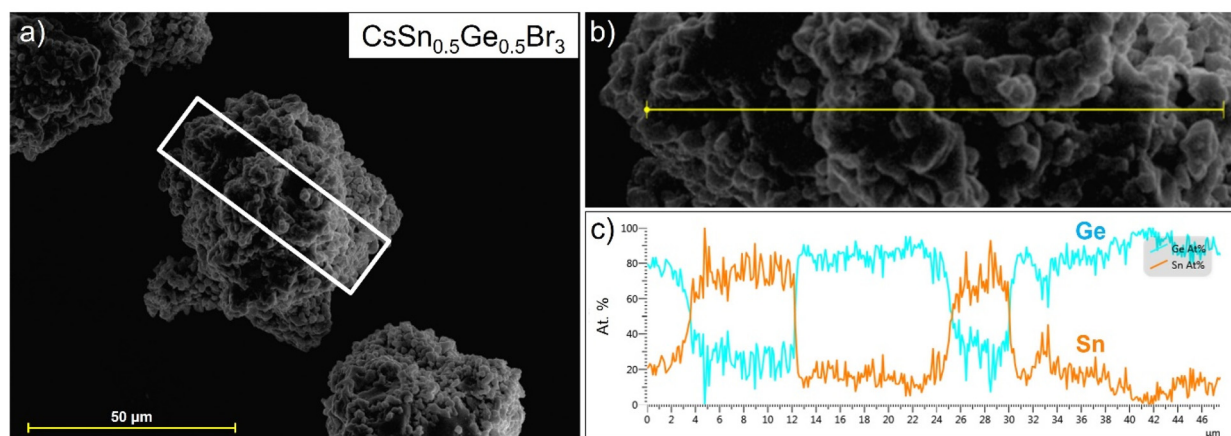


Fig. 3 (a) Electron micrograph of SS-prepared $\text{CsSn}_{0.5}\text{Ge}_{0.5}\text{Br}_3$, with box outlining region of line scan. (b) Expanded view of region. (c) Atomic percents of Sn (orange) and Ge (teal).

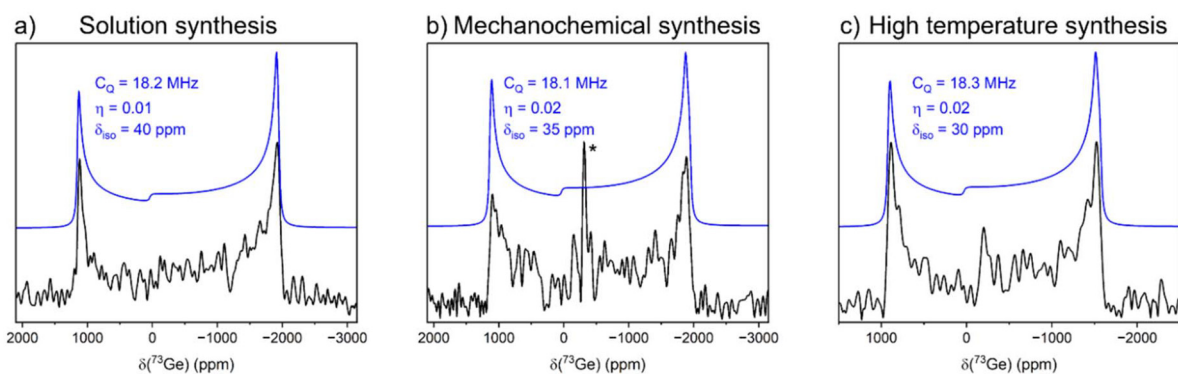


Fig. 4 Non-spinning ^{73}Ge NMR spectra (experimental in black, fit in blue) at 18.8 T for (a) SS and (b) MCS, and at 21.1 T for (c) HT CsGeBr_3 . The asterisk, *, marks a GeBr_4 impurity.



Table 2 Experimental and DFT-computed ^{73}Ge NMR parameters for CsGeBr_3 were prepared via SS, MCS, and HT routes

CsGeBr_3	C_Q (MHz)		η		δ_{iso} (expt)/ σ_{iso} (calc)		Ω^a (ppm)		κ	
	Expt	Calc	Expt	Calc	Expt	Calc	Expt	Calc	Expt	Calc
SS	18.2(1)	22.30	0.01(1)	0.00	40(8)	1402.24	n.d.	29.61	n.d.	0.00
MCS	18.1(1)	23.10	0.02(1)	0.00	35(10)	1389.70	n.d.	31.78	n.d.	0.00
HT	18.3(1)	22.67	0.02(1)	0.00	30(12)	1398.57	n.d.	34.46	n.d.	0.00

^a CSA was not determined (n.d.).

thetic method (Fig. 5). Peaks occur at -347 ppm for SS and -265 ppm for MCS samples, but at a higher frequency of 670 ppm for the HT sample. Their linewidths increase in the order of 19 kHz for SS, 39 kHz for MCS, and 57 kHz for HT samples, similar to previous reports indicating sensitivity to the synthetic method.^{62,65,75} The line shapes are symmetric for the MCS and HT samples, but show tailing toward higher frequency for the SS sample, which matches an earlier report in which the authors attribute this shoulder to gradients in free-carrier concentration across solution-grown microcrystals.⁷⁵ To ensure no hidden resonances are present, the corresponding ^{119}Sn MAS NMR spectrum for SS CsSnBr_3 is shown in Fig. S25, revealing no other degradation or impurity-related species.

Previous reports for HT-synthesized CsSnBr_3 also showed that the ^{119}Sn NMR chemical shift appears at a higher frequency than SS and MCS samples, but not to the same extent as described here; the value depends strongly on the synthesis temperature and duration (e.g., from -289 to -179 ppm for samples prepared by similar methods).^{62,65,75} The origin of this chemical shift dependence is unclear but it may arise from a combination of factors, including changes in the local Sn environment (including the expression of a stereochemically active lone pair), defect concentration, and sample

degradation.^{23,62,65,75} The significant difference in chemical shift between the HT and SS or MCS samples is reminiscent of a Knight shift or paramagnetic interactions, which would not typically be expected for a diamagnetic sample such as CsSnBr_3 . However, light-induced paramagnetic defects of Pb^{3+} and Pb^0 have recently been proposed to affect the NMR spectra of related lead halide perovskites.^{76,77} Similarly, paramagnetic Sn^{3+} centres have been observed in SrSnO_3 ,⁷⁸ as well as metallic Sn in degraded MASnI_3 ,²³ and most recently, the observation of a carrier-dependent Knight shift contribution to ^{119}Sn chemical shifts for CsSnBr_3 .⁷⁵ To investigate the hypothesis that paramagnetic species could be responsible for the large chemical shift difference in HT CsSnBr_3 , its EPR spectrum was collected (Fig. S27). A signal was detected at an isotropic g -value of 2.003 ± 0.001 , providing evidence of a paramagnetic contribution. Unfortunately, the specific Sn speciation present or why this effect is so pronounced only in the HT sample remain unclear at this time.

^{81}Br NQR of CsGeBr_3 and CsSnBr_3

There has been renewed interest in applying NQR spectroscopy as a powerful tool for studying quadrupolar nuclei in various materials, including perovskites.^{58,79–88} Through the quadrupolar interaction mediated by the electric-field gradient (EFG) at the nucleus, NQR spectroscopy offers high sensitivity for probing local chemical environments and discerning subtle changes in site symmetry and disorder. The Br sites within the CsGeBr_3 and CsSnBr_3 samples were examined by their ^{81}Br (49.31% abundance, $I = 3/2$, $\gamma = 7.2498 \times 10^7 \text{ rad T}^{-1} \text{ s}^{-1}$, $Q = 26.15 \text{ fm}^2$) NQR spectra (Fig. 6). The SS samples exhibit much narrower linewidths than the MCS and HT samples, consistent with their higher degree of crystallinity and larger crystallites (Fig. 2). In contrast, the MCS samples are known to contain smaller crystallites with more defects^{60,62,89,90} leading to wider EFG distributions and shorter nuclear spin–spin relaxation times, which cause spectral broadening. The spectra were fitted to extract NQR parameters (Fig. S28), which were compared with DFT computed values (Table 3).

For both compounds, the SS samples always produce the lowest NQR frequency, ν_Q , consistent with high crystallinity. For CsGeBr_3 , the quadrupole coupling constant, C_Q , does not depend on the synthetic method. For CsSnBr_3 , the values vary considerably with the synthetic method, although the ν_Q values fall within typical ranges from the literature.⁹¹ The larger C_Q value for the HT method further supports a more

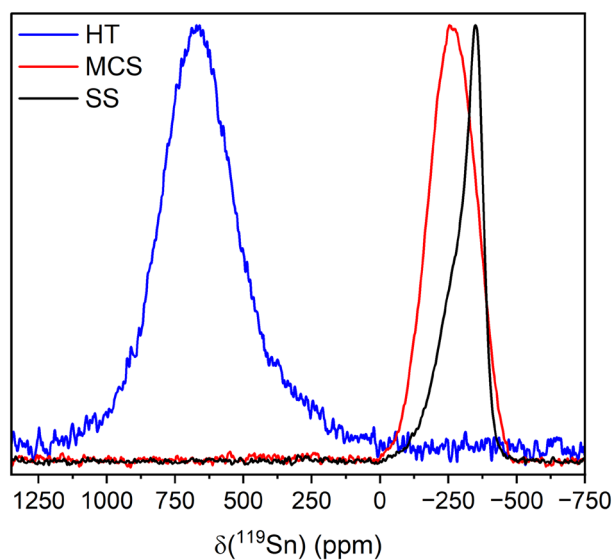


Fig. 5 Non-spinning ^{119}Sn NMR spectra (11.7 T) for SS, MCS, and HT-prepared CsSnBr_3 .



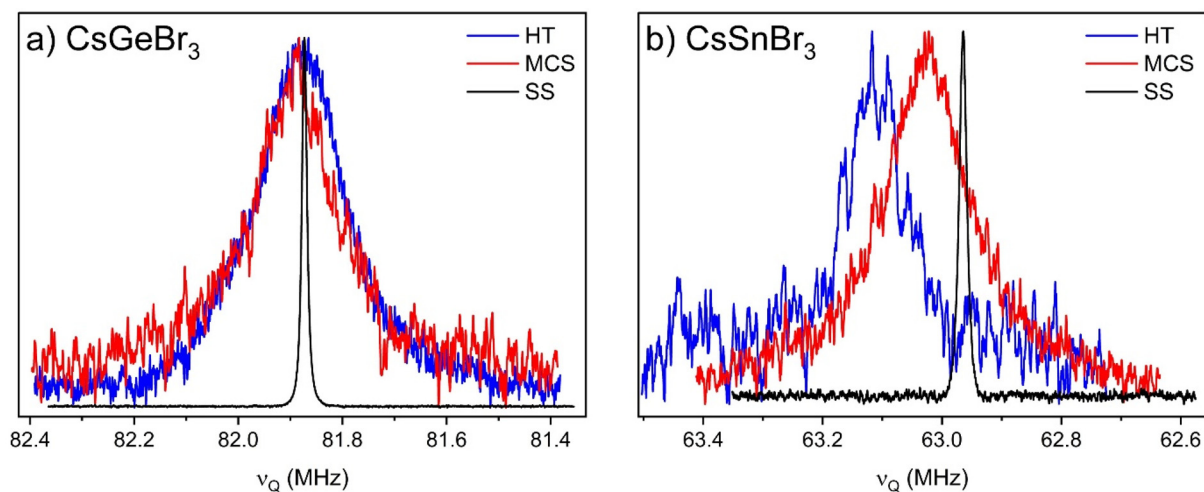


Fig. 6 ^{81}Br NQR spectra for (a) CsGeBr_3 and (b) CsSnBr_3 .

Table 3 Experimental and DFT computed ^{81}Br NMR and NQR parameters for CsGeBr_3 and CsSnBr_3 prepared via SS, MCS, and HT routes

Sample	NQR			NMR			
	$ \nu_Q $ (MHz)		FWHM (kHz) Expt (± 0.2)	C_Q (MHz)		η	
	Expt	Calc		Expt ^a	Calc	Expt	Calc
CsGeBr_3							
SS	81.873	91.30	11.4	163.746(1)	182.60	0.000(5)	0.00
MCS	81.884	90.70	180.6	163.775(10)	181.40	0.000(10)	0.01
HT	81.879	90.85	209.5	163.764(8)	181.70	0.000(10)	0.01
CsSnBr_3							
SS	62.957	73.85	19.2	125.933(2)	147.70	0.000(8)	0.00
MCS	63.025	73.85	225.4	126.057(10)	147.70	0.000(20)	0.00
HT	63.110	73.85	156.9	126.225(10)	147.70	0.000(15)	0.00

^a Sign of C_Q could not be determined experimentally.

strained EFG, which may be induced from a larger lone-pair effect on Sn, while the overall paramagnetic species reduces the S/N of the spectrum due to fast relaxation. Comparing with DFT, similar to what is observed for ^{73}Ge , there is a systematic overestimation of the C_Q values for each input structure, while no significant change or trend can be observed from the ^{81}Br NMR parameters computed for either CsGeBr_3 or CsSnBr_3 . Still, *a priori* estimation of the ν_Q values from DFT assist to define a range for experimental acquisition of the desired signal. Lastly, in conjunction with the discussion above about the varied ^{119}Sn NMR spectra of CsSnBr_3 , synthetic treatments have been proposed to affect Br dynamics in tin halide perovskites,^{62,92} which can be significant enough to result in ionic conductivity at room temperature.⁹³

MCS-synthesized solid solution $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$

The XRD data for MCS and HT $\text{CsSn}_{0.5}\text{Ge}_{0.5}\text{Br}_3$ samples can be refined to both trigonal and cubic models, while exhibiting homogeneous B-site elemental distribution through EDX with broad ^{133}Cs NMR signals spanning the trigonal CsGeBr_3 and cubic CsSnBr_3 chemical shift ranges. These results demon-

strate the ambiguity that can remain when only examining materials at either the local or extended length scales. The observation that SS $\text{CsSn}_{0.5}\text{Ge}_{0.5}\text{Br}_3$ is a heterogeneous mixture of Sn- and Ge-rich compositions of roughly $\text{CsSn}_{0.2}\text{Ge}_{0.8}\text{Br}_3$ and $\text{CsSn}_{0.8}\text{Ge}_{0.2}\text{Br}_3$ from these same techniques further demonstrates that in all cases, there can be gradients in elemental distributions throughout a bulk sample. To further study the behaviour of B-site mixing in $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$, a series of samples of varying composition were synthesized by MCS.

Additional members of the $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$ series were prepared by MCS routes with nominal compositions at $x = 0, 0.10, 0.25, 0.50, 0.75, 0.90, 1$. Based on EDX of the resulting samples, the obtained phases had actual compositions of $x = 0, 0.14, 0.28, 0.54, 0.66, 0.91, 1$ (Table S6 and Fig. S13–S19). These samples were then examined by diffuse reflectance spectroscopy, Raman spectroscopy, ^{133}Cs and ^{119}Sn NMR spectroscopy, and powder XRD.

The diffuse reflectance spectra were converted to Tauc plots with the assumption of direct band gaps (Fig. 7a and S8). The band gap decreases gradually from 2.5 to 1.8 eV with greater Sn substitution on proceeding from CsGeBr_3 to CsSnBr_3 . The



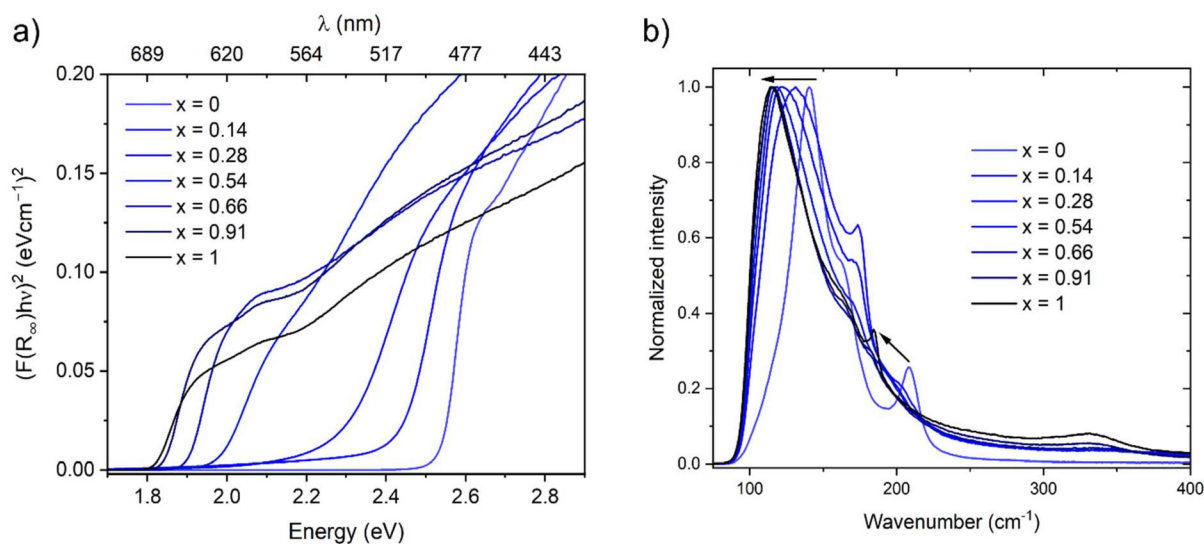


Fig. 7 (a) Diffuse reflectance spectra converted to Tauc plots and (b) Raman spectra for $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$.

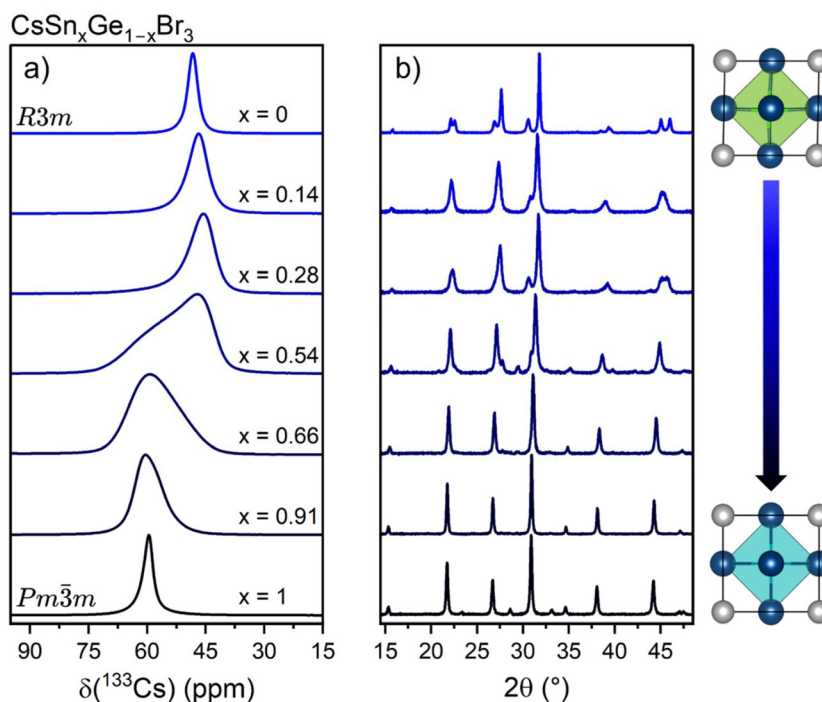


Fig. 8 (a) ^{133}Cs NMR spectra and (b) powder XRD patterns for MCS $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$ samples. Trigonal CsGeBr_3 shows a slight distortion (top) relative to cubic CsSnBr_3 (bottom).

Raman spectra show major features corresponding to phonon scattering modes at $140 [\text{E}_{\text{TO}}^4]$, $162 [\text{A}_{\text{TO}}^3]$, and $208 \text{ cm}^{-1} [\text{A}_{\text{LO}}^3]$ for CsGeBr_3 , as assigned by Huang *et al.*,⁹⁴ and at $114 [\text{T}_{\text{TO}}^3]$ and $184 \text{ cm}^{-1} [\text{T}_{\text{LO}}^3]$ for CsSnBr_3 (Fig. 7b).⁹⁵ Greater Sn substitution generally shifts the Raman peaks to lower wavenumber.

As before, the ^{133}Cs NMR spectra show a single resonance with δ_{iso} of 48 ppm for trigonal CsGeBr_3 and 60 ppm for cubic

CsSnBr_3 (Fig. 8a and Table 4). As Sn substitutes for Ge in CsGeBr_3 , the peak gradually shifts to lower frequency until $x = 0.54$, at which point the signal is maximally broadened to encompass the high frequency region characteristic of the $\text{Pm}\bar{3}m$ CsSnBr_3 . At higher Sn concentrations, only the high frequency peak centred at 60 ppm remains; it does not shift but only becomes gradually narrower. ^{133}Cs T_1 relaxation measurements were performed for the series (Fig. S5), which begin at a



Table 4 Cell parameters and ^{133}Cs NMR data for MCS-prepared $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$.^a Compositions as measured via EDX are used to constrain Rietveld refinements for analysis

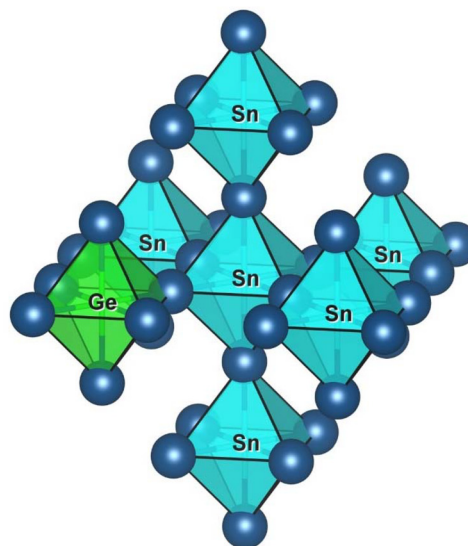
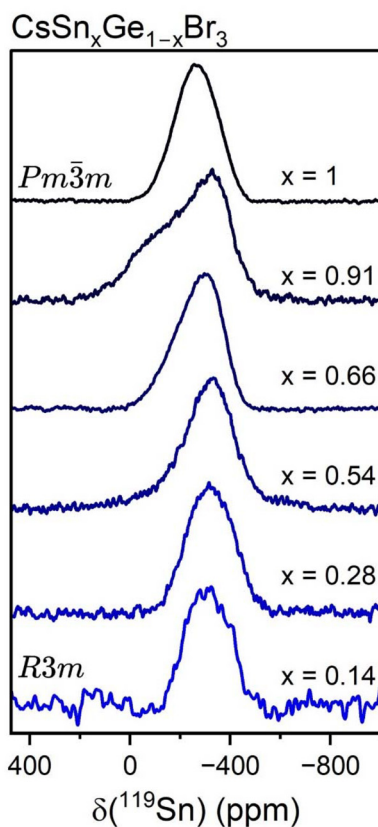
Sample	a (Å)	α (°)	δ_{iso} (ppm) ± 1	T_1 (s)	FWHM (Hz)	Band gap (eV)
CsGeBr_3 ($R3m$)	5.6505	88.84	48	112	240	2.5
$\text{CsSn}_{0.14}\text{Ge}_{0.86}\text{Br}_3$ ($R3m$)	5.6542	89.21	47	92	470	2.4
$\text{CsSn}_{0.28}\text{Ge}_{0.72}\text{Br}_3$ ($R3m$)	5.6662	89.37	46	70	590	2.3
$\text{CsSn}_{0.54}\text{Ge}_{0.46}\text{Br}_3$ ($R3m$)	5.6624	89.53	47	31	1450	2.0
$\text{CsSn}_{0.54}\text{Ge}_{0.46}\text{Br}_3$ ($Pm\bar{3}m$)	5.7495	90	57			
$\text{CsSn}_{0.66}\text{Ge}_{0.34}\text{Br}_3$ ($Pm\bar{3}m$)	5.7744	90	60	32	1180	1.9
$\text{CsSn}_{0.91}\text{Ge}_{0.09}\text{Br}_3$ ($Pm\bar{3}m$)	5.7960	90	61	22	640	1.8
CsSnBr_3 ($Pm\bar{3}m$)	5.8039	90	60	24	235	1.8

^a Estimated errors are 0.0002 Å for a , 0.02° for α (except for 90°, which is exact), <0.5 s for T_1 , ± 5 –30 Hz for FWHM, and ± 0.05 eV for band gap. The cell parameters for the trigonal structural models in $R3m$ correspond to a primitive rhombohedral cell to facilitate comparison to the cubic model.

maximum of 112 s for CsGeBr_3 and gradually shorten on proceeding to CsSnBr_3 ($T_1 = 24$ s). ^{119}Sn relaxation has been shown to be sensitive to Br^- dynamics in CsSnBr_3 and MASnBr_3 .^{62,92} While MCS induces defects and generates nano/microcrystalline powders, which can decrease spin–lattice relaxation, the ^{133}Cs T_1 values are also influenced by the crystal structure and elemental composition. Specifically, the Ge-rich phases have longer relaxation times, suggesting that the Br^- rearrangement contributes to T_1 shortening when Sn is introduced into the structure. Thus, the interplay of elemen-

tal disorder, defect concentration, halogen rearrangement (if present) and structure all impact the spin–lattice relaxation and are difficult to disentangle in these solid-solutions.

The powder XRD patterns show that the splitting characteristic (*e.g.*, diffraction peaks near 22° and 27° in 2θ) of the trigonal structure of CsGeBr_3 is no longer apparent even at $x = 0.14$ (Fig. 8b). This splitting could well be obscured because the diffraction peaks are broadened as a result of the ball-milling processes, which typically impart significant defects and strain. Based on the NMR data, the samples were assumed to

**Fig. 9** Non-spinning ^{119}Sn NMR spectra for $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$ (left). Model for local environment of a Sn-centred octahedron with connectivity to symmetry-breaking Ge-centred octahedron in $\text{CsSn}_{0.91}\text{Ge}_{0.09}\text{Br}_3$ (right).

adopt the trigonal structure for $x = 0-0.28$, both trigonal and cubic structures at $x = 0.54$, and cubic structures beyond this point. For the Ge-rich samples, the cell angle α based on a primitive rhombohedral cell is very close to 90° (Table 4). For the Sn-rich samples with cubic structures, the cell length a is gradually lengthened on proceeding from the midpoint of the solid solution to the end member CsSnBr_3 .

The tetrel site in $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$ was probed by ^{119}Sn NMR spectroscopy. In contrast to the discussions above, here it is sensible to start with the end member CsSnBr_3 and examine the trends as Ge substitutes for Sn. In general, the NMR spectra consist of a broad, symmetric resonance that shifts slightly to lower frequency and exhibits a lower signal-to-noise ratio due to the reduced amount of Sn with greater Ge substitution (Fig. 9). The only perceptible change occurs in $\text{CsSn}_{0.91}\text{Ge}_{0.09}\text{Br}_3$, which shows a CSA-dominated line shape arising from interactions with the rare Ge-centred octahedron interrupting the network of Sn-centred octahedra. The presence of CSA in $\text{CsSn}_{0.91}\text{Ge}_{0.09}\text{Br}_3$ was confirmed by the complete disappearance of the CSA broadened line shape when acquired under MAS NMR (Fig. S26). By virtue of the neighbouring Ge-centred octahedron, there is a deviation from axial symmetry around the Sn atom. If this model is accepted, the simulated CSA line shape has a span of $\Omega = 410 \pm 10$ ppm and a skew κ of -0.68 ± 0.03 . No attempts were made to obtain ^{73}Ge NMR spectra due to the sensitivity associated with a large second-order quadrupolar line shape and the low germanium concentration resulting from Sn substitution.

Trends in band gap, relaxation times, and structure

The results obtained up to this stage are now combined to identify general trends in how various properties of $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$ depend on Sn content and synthetic method (Fig. 10).

The band gaps appear to lie within two groups, with larger gaps for the Ge-rich trigonal phases and smaller ones for the Sn-rich cubic phases (Fig. 10a). Within each group, the band gap decreases roughly linearly, as indicated by fits to linear equations for the MCS samples. The band gap is tuneable within these groups. The choice of synthetic method introduces variations in the band gap; for a given nominal composition, SS samples consistently exhibit smaller gaps by about 0.1 eV.

The ^{133}Cs spin-lattice relaxation times shorten considerably on proceeding from CsGeBr_3 to CsSnBr_3 (Fig. 10b), consistent with previous proposals that Br rearrangements are much more pronounced in Sn-containing perovskites, including the end member CsSnBr_3 .⁶² The relaxation times are highly dependent on the synthetic method. The relaxation times are extremely long for the SS samples, implying better crystallinity, whereas they are always the shortest for the MCS samples, which consist of smaller, poorly formed particles with presumably greater defect concentrations.

Substituting Ge with larger Sn atoms is expected to expand the unit cell, but the cell parameters also appear to fall within two groups (Fig. 10c). Based on the trends in the cell length a and the cell angle α , the discontinuity midway suggests a

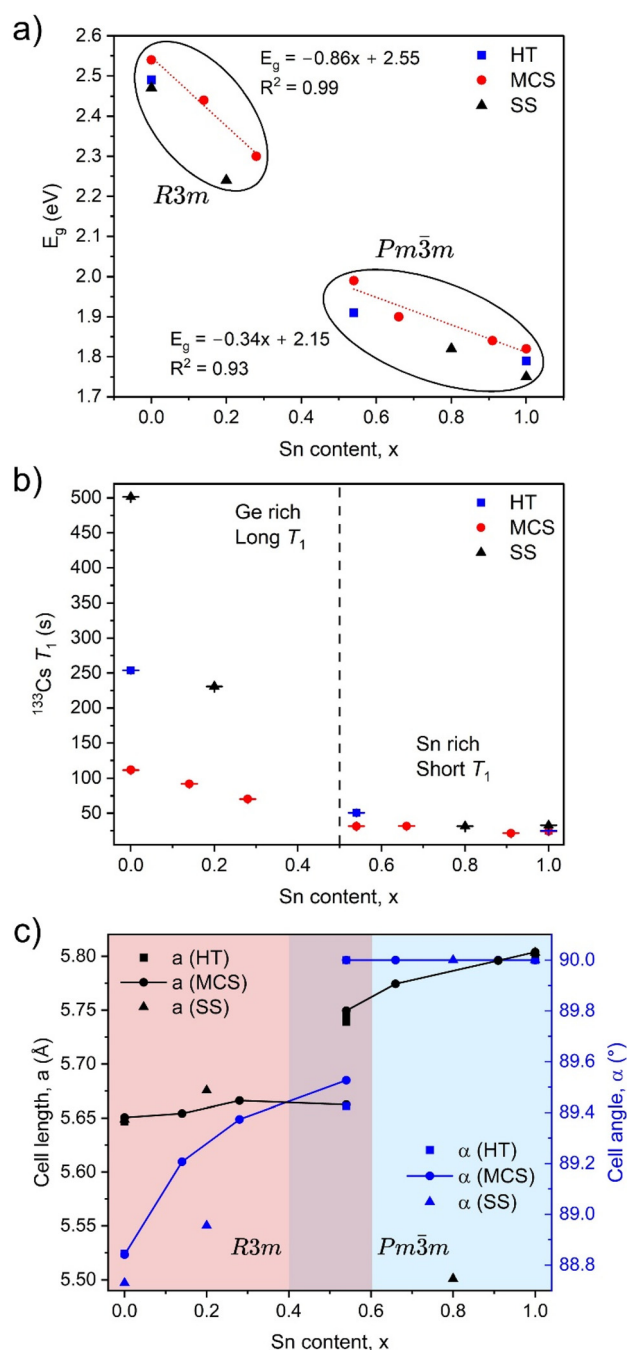


Fig. 10 Trends in (a) band gaps, (b) ^{133}Cs relaxation times, and (c) cell parameters as a function of Sn content in $\text{CsSn}_x\text{Ge}_{1-x}\text{Br}_3$ samples prepared by SS, MCS, and HT routes.

miscibility gap (estimated to be $0.4 < x < 0.6$) between the trigonal structure for Ge-rich samples and the cubic structure for Sn-rich samples. As the Sn content increases, the cell angle α mainly increases within the trigonal structure whereas the cell length a increases within the cubic structure. Similar to the trends in ^{133}Cs NMR relaxation times, the SS-prepared samples tend to be outliers, giving smaller unit cells than the HT and MCS samples.



Summarizing the diffraction, NMR, and microscopy results, the solvent synthesis approach is the most effective for producing highly crystalline solids, as it facilitates nucleation and allows large crystallites with well-defined morphologies to form. In contrast, the high energy shear forces from mechanochemical ball milling produce coarser materials with less uniform particles and a larger degree of structural variations of the local- and medium-range polyhedra. Likewise, MCS leads to crystal defects within the structure. HT samples exist in the intermediate regime between SS and MCS, with less local disorder compared to MCS samples, but with the added complication of the formation of a paramagnetic species in the pure Sn phase. The subtle changes in local structure, crystallinity, defects and paramagnetic species clearly influence the optical properties of these materials. These influences may have even greater consequence concerning the intrinsic ferroelectric properties of CsGeBr₃ (governed by the degree of Ge off-centring in [GeBr₆]⁴⁻ octahedra), or the metallic/ionic conductivity reported for CsSnBr₃, and how the presence of Sn(III)/Sn(0) centres, or the Ge/Sn²⁺ active lone pair may influence these properties.

Conclusions

This study provides a comprehensive overview of the crucial aspects of material design for the CsSn_xGe_{1-x}Br₃ system. By combining diffraction methods and localized probing techniques, notably NMR and NQR spectroscopy, it has been determined that the optical characteristics of these lead-free perovskites are significantly influenced by the interplay between their composition and synthetic methodology. Understanding the structure and the effects of differing processing conditions on a material is crucial for rational material design, with structure–property relationships governing all aspects of applications-guided material synthesis. The structural characterization reveals a composition-dependent phase transition, with a miscibility gap occurring near the 1 : 1 composition. The series transitions from a trigonal Ge-rich phase with distorted octahedra to a cubic Sn-rich phase, forming two distinct groups. Each group exhibits adjustable optical band gaps following a linear dependence on *x* in each region rather than changing continuously. Solvent synthesis produces highly crystalline particles with low defect densities as shown by narrow NMR linewidths and long nuclear spin–lattice relaxation times but suffers from phase segregation in the Sn–Ge mixed case. In contrast, mechanochemical and high-temperature approaches improve macroscopic mixing of B-site cations but introduce significant lattice strain and more defects. This is especially evident in the high-temperature sample, where EPR spectroscopy reveals paramagnetic defects that may cause the substantial ¹¹⁹Sn chemical shift changes observed. Further investigation of this complex compositional space with focus on applications-based performance and stability tests is essential since material homogeneity, structure, and optical properties vary with preparation method and composition. Characterization across multiple length scales is an essential

component for these materials, particularly as site disorder and ion mixing complicate analysis using traditional methods.

Conflicts of interest

There are no conflicts to declare.

Data availability

The data supporting this article are provided in the supplementary information (SI). Supplementary information: X-ray diffraction, solid-state NMR spectroscopy, diffuse reflectance, electron microscopy and energy dispersive X-ray spectroscopy, NQR spectroscopy, EPR spectroscopy, DFT calculations. Further experimental details. See DOI: <https://doi.org/10.1039/d6qi00612d>.

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